IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	)	
	)	
Min-hwa Chi	)	Examiner: D. Kang
	)	
Serial No. not yet assigned	)	Art Unit: 2811
	)	
Filed: 5/24/01	)	
	)	
For: TRANSISTOR AND LOGIC CIRCUIT ON THIN SILICON-ON-INSULATOR WAFERS BASED ON GATE INDUCED DRAIN LEAKAGE CURRENTS	)	

Assistant Commissioner for Patents
Washington, DC 20231

PRELIMINARY AMENDMENT

Sir or Madam:

Prior to examination of the above referenced application, Applicant respectfully request the Examiner to cancel Claims 1-10 and 19-26.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR and ZAFMAN

Dated: 5/24/01

Chun M. Ng
Reg. No. 36,878